

Zener diode 12V±2%, If=200mA, 300mW SOD-523 6d 1a Phi

Manufacturers	<u>NXP Semiconductor</u>
Package/Case	SOD523
Product Type	Diodes & Rectifiers
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BZX585-B12 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BZX585-B12 is a type of Zener diode, which is a semiconductor device that is designed to operate in the reverse breakdown region of its VI characteristics. The BZX585-B12 Zener diode is specifically designed to have a breakdown voltage of 12 volts.

Features

Zener voltage: 12V

Power dissipation: 300mW

Package type: SOD-523

Application

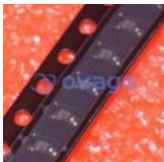
Voltage regulation

Overvoltage protection

Signal conditioning



Related Products



[BZX384-B5V1](#)

NXP Semiconductor
SOD-323



[BZV55-B5V1](#)

NXP Semiconductor
SOD-80C



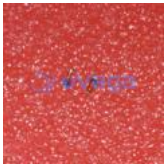
[BZX384-C4V7](#)

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